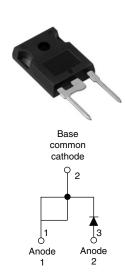


Vishay High Power Products

HEXFRED® Ultrafast Soft Recovery Diode, 6 A



TO-247AC modified

PRODUCT SUMMARY				
V _R	1200 V			
V _F at 6 A at 25 °C	3.0 V			
I _{F(AV)}	6 A			
t _{rr} (typical)	26 ns			
T _J (maximum)	150 °C			
Q _{rr} (typical)	116 nC			
dl _{(rec)M} /dt (typical) at 125 °C	100 A/μs			
I _{RRM} (typical)	4.4 A			

FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- · Specified at operating temperature
- Lead (Pb)-free
- · Designed and qualified for industrial level

BENEFITS

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- · Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

DESCRIPTION

HFA06PB120 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 6 A continuous current, the HFA06PB120 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA06PB120 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V _R		1200	V	
Maximum continuous forward current	I _F	T _C = 100 °C	6		
Single pulse forward current	I _{FSM}		80	Α	
Maximum repetitive forward current	I _{FRM}		24		
Maximum nawar discination	P _D	T _C = 25 °C	62.5	w	
Maximum power dissipation		T _C = 100 °C	25]	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C	

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

HFA06PB120PbF

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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	/ _{BR}		-	ı	
Maximum forward voltage V _{FM}	I _F = 6.0 A	ı	2.7	3.0	V	
	I _F = 12 A	-	3.5	3.9		
	I _F = 6.0 A, T _J = 125 °C	-	2.4	2.8		
Maximum reverse Ieakage current		$V_R = V_R$ rated	-	0.26	5.0	
		$T_J = 125$ °C, $V_R = 0.8 \times V_R$ rated	-	110	500	μΑ
Junction capacitance	C _T	V _R = 200 V	-	9.0	14	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body -		8.0	-	nH

DYNAMIC RECOVERY CHARACTERISTICS (T _C = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t _{rr}	I _F = 1.0 A, dI _F /dt = 200 A/μs, V _R = 30 V		-	26	-	
Reverse recovery time	t _{rr1}	T _J = 25 °C	I _F = 6.0 A dI _F /dt = 200 A/μs V _R = 200 V	-	53	80	ns
	t _{rr2}	T _J = 125 °C		-	87	130	
Peak recovery current	I _{RRM1}	T _J = 25 °C		-	4.4	8.0	A
	I _{RRM2}	T _J = 125 °C		-	5.0	9.0	
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	116	320	nC - A/µs
neverse recovery charge	Q _{rr2}	T _J = 125 °C		-	233	585	
Peak rate of recovery current	dI _{(rec)M} /dt1	T _J = 25 °C		-	180	-	
during t _b	dI _{(rec)M} /dt2	T _J = 125 °C		-	100	-	Ανμδ

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R _{thJC}		-	-	2.0	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	K/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-	
Moight			-	2.0	-	g
Weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AC modified		HFA06	PB120	



HEXFRED® Vishay High Power Products Ultrafast Soft Recovery Diode, 6 A

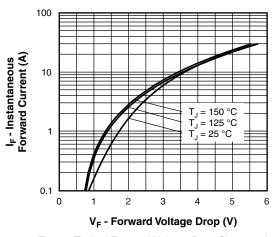


Fig. 1 - Typical Forward Voltage Drop Characteristics

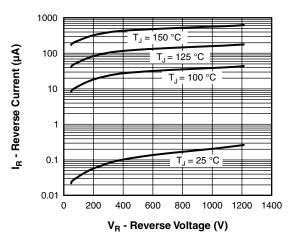


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

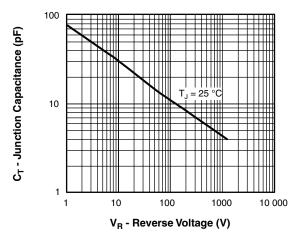


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

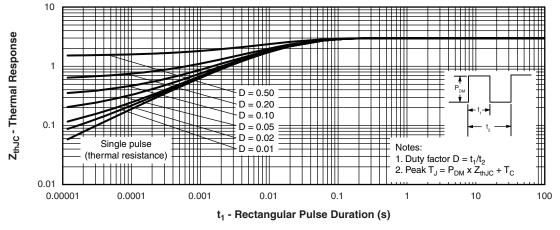


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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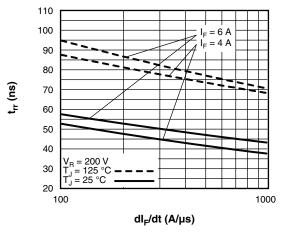


Fig. 5 - Typical Reverse Recovery Time vs. dI_F/dt

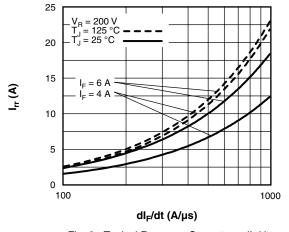


Fig. 6 - Typical Recovery Current vs. dI_F/dt

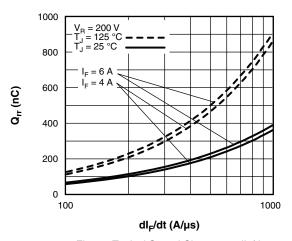


Fig. 7 - Typical Stored Charge vs. dl_F/dt

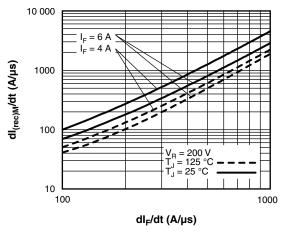


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt



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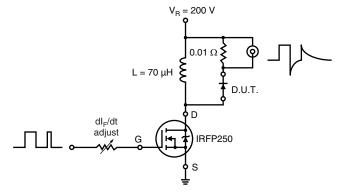
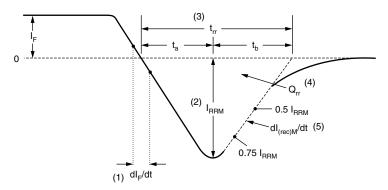


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $t_{\rm rr}$ reverse recovery time measured from zero crossing point of negative going $I_{\rm F}$ to point where a line passing through 0.75 $I_{\rm RRM}$ and 0.50 $I_{\rm RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

HFA06PB120PbF

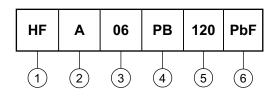
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ORDERING INFORMATION TABLE

Device code



1 - HEXFRED® family

2 - Process designator:

A = A subs. elec. irrad.

B = B subs. platinum

3 - Average current: 06 = 6 A

- Package outline: PB = TO-247 2 lead

Voltage code: 120 = 1200 V

6 - • None = Standard production

• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95253					
Part marking information	http://www.vishay.com/doc?95255				



Vishay

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Revision: 18-Jul-08

Document Number: 91000 www.vishay.com